### KBPC50005W THRU KBPC5010W

#### HIGH CURRENT SINGLE-PHASE SILICON BRIDGE RECTIFIERS

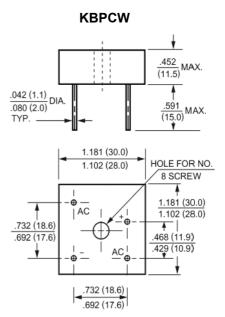
**REVERSE VOLTAGE: 50 to 1000 VOLTS FORWARD CURRENT: 50 AMPERES** 

#### **Features**

- Electrically isolated metal case for maximum heat dissipation
- Surge overload ratings to 500 A
- Low power loss, high efficiency
- · Low reverse leakage current
- Case to terminal isolation voltage 2500 V
- UL recognized file # E-216968

#### Mechanical data

- Metal or molded plastic with heatsink integrally mounted in the bridge encapsulation
- Mounting Position: Any



Dimensions in inches and (mm)

### **Absolute Maximum Ratings and Characteristics**

Rating at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Parameter	Symbols	KBPC 50005W	KBPC 5001W	KBPC 5002W	KBPC 5004W	KBPC 5006W	KBPC 5008W	KBPC 5010W	Units
Maximum Recurrent Peak Reverse Voltage	$V_{RRM}$	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	$V_{RMS}$	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	$V_{DC}$	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current at $T_C = 55$ °C	I <sub>(AV)</sub>	50							Α
Peak Forward Surge Current, 8.3 ms Single Half-Sine -Wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	400						Α	
Maximum Forward Voltage at 25 A DC and 25 °C	$V_{F}$	1.2						V	
Maximum Reverse Current at $T_A = 25$ °C at Rated DC Blocking Voltage $T_A = 125$ °C	I <sub>R</sub>	10 1000							μА
Typical Junction Capacitance 1)	CJ	300						pF	
Typical Thermal Resistance 2)	$R_{\theta JC}$	2.6						°C/W	
Operating and Storage Temperature Range	$T_J,T_S$	-55 to +150							°C

<sup>1)</sup> Measured at 1 MHz and applied reverse voltage of 4 VDC.

<sup>&</sup>lt;sup>2)</sup> Thermal resistance from junction to case per leg.



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Dated: 15/02/2006 H

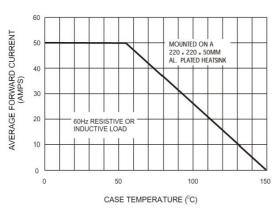


Figure 1. Forward Current Derating Curve

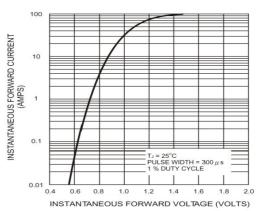


Figure 2. Typical Instantaneous Forward Characteristics Per Brdige Element

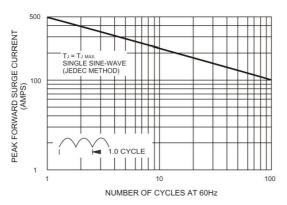


Figure 3. Maximum Non-repetitive Peak Forward Surge Current Per Bridge Element

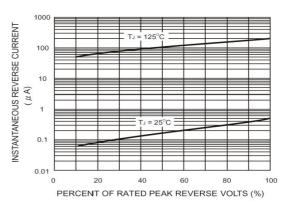


Figure 4. Typical Reverse Leakage Characteristics Per Bridge Element

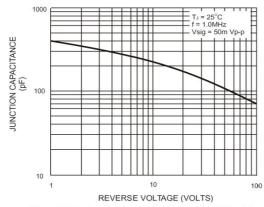
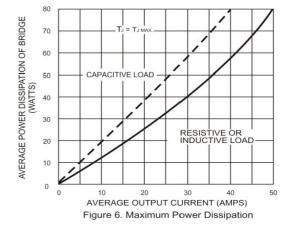


Figure 5. Typical Junction Capacitance Per Bridge Element





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